

BCR112WE6327BTSA1

BCR112WE6327BTSA1 Information



For Reference Only

Part Number	BCR112WE6327BTSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single, Pre-Biased
Description	TRANS PREBIAS NPN 250MW SOT323-3
Package	SC-70, SOT-323
	For the pricing/inventory/lead time, please contact us Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



BCR112WE6327BTSA1 Specifications

Manufacturer Part Number	BCR112WE6327BTSA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single, Pre-Biased
Package	SC-70, SOT-323
Series	-
Transistor Type	NPN - Pre-Biased
Current - Collector (Ic) (Max)	100mA
Voltage - Collector Emitter Breakdown (Max)	50V
Resistor - Base (R1) (Ohms)	4.7k
Resistor - Emitter Base (R2) (Ohms)	4.7k
DC Current Gain (hFE) (Min) @ Ic, Vce	20 @ 5mA, 5V
Vce Saturation (Max) @ Ib, Ic	300mV @ 500µA, 10mA
Current - Collector Cutoff (Max)	100nA (ICBO)
Frequency - Transition	140MHz
Power - Max	250mW
Mounting Type	Surface Mount
Package / Case	SC-70, SOT-323
Supplier Device Package	PG-SOT323-3
	Report errors?

BCR112WE6327BTSA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

BCR112WE6327BTSA1 Payment Methods





BCR112WE6327BTSA1 Shipping Methods



If you have any question about BCR112WE6327BTSA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com